



USSP5520

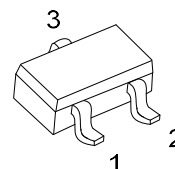
Preliminary

PNP EPITAXIAL SILICON TRANSISTOR

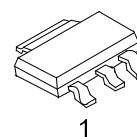
-20V, -5.0A PNP LOW $V_{CE(SAT)}$ TRANSISTOR

FEATURES

- * Low collector-emitter saturation voltage $V_{CE(SAT)}$
- * High collector current capability: I_C and I_{CM}
- * Higher efficiency leading to less heat generation
- * Reduced printed-circuit board requirements
- * Complement: USSN5520



SOT-23
(EIAJ SC-59)

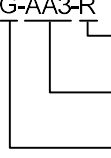


SOT-223

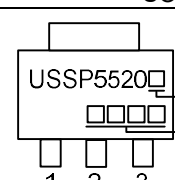
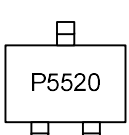
ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
USSP5520L-AA3-R	USSP5520G-AA3-R	SOT-223	B	C	E	Tape Reel
USSP5520L-AE3-R	USSP5520G-AE3-R	SOT-23	B	E	C	Tape Reel

Note: Pin Assignment: B: Base C: Collector E: Emitter

USSP5520G-AA3-R 	(1) R: Tape Reel (2) AA3: SOT-223. AE3: SOT-23 (3) G: Halogen Free and Lead Free, L: Lead Free
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MARKING

SOT-223	SOT-23
 L: Lead Free G: Halogen Free Date Code	 P5520

■ ABSOLUTE MAXIMUM RATING (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V _{CBO}	-20	V
Collector-Emitter Voltage		V _{CEO}	-20	V
Emitter-Base Voltage		V _{EBO}	-5	V
Collector Current	DC	I _C	-5	A
	Peak	I _{CM}	-10	A
Power Dissipation (T _A ≤ 25°C)	SOT-223	P _D	1	W
	SOT-23		0.35	W
Junction Temperature		T _J	+150	°C
Storage Temperature		T _{STG}	-65 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
 2. Device mounted on a FR4 printed-circuit board, single-sided copper; tin-plated, mounting pad for collector 1 cm².

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	SOT-223	θ _{JA}	125	°C/W
	SOT-23		357	°C/W
Junction to Case	SOT-223	θ _{JC}	15	°C/W
	SOT-23		100	°C/W

Note: Device mounted on a FR4 printed-circuit board, single-sided copper; tin-plated, mounting pad for collector 1 cm².

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV _{CBO}	I _C =-100μA, I _E =0	-20			V
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =-1mA, I _B =0	-20			V
Emitter-Base Breakdown Voltage	BV _{EBO}	I _E =-100μA, I _C =0	-5			V
Collector-Base Cut-Off Current	I _{CBO}	V _{CB} =-20V, I _E =0			-100	nA
		V _{CB} =-20V, I _E =0, T _J =150°C			-50	μA
Collector-Emitter Cut-Off Current	I _{CES}	V _{CE} =-20V, V _{BE} =0			-100	nA
Emitter-Base Cut-Off Current	I _{EBO}	V _{EB} =-5V, I _C =0			-100	nA
Collector-Emitter Saturation Voltage (Note)	V _{CE(SAT)}	I _C =-500mA, I _B =-50mA			-100	mV
		I _C =-1A, I _B =-50mA			-150	mV
		I _C =-2A, I _B =-200mA			-200	mV
		I _C =-4A, I _B =-400mA			-500	mV
		I _C =-5A, I _B =-500mA			-600	mV
Base-Emitter Saturation Voltage (Note)	V _{BE(SAT)}	I _C =-4A, I _B =-400mA			-1.1	V
		I _C =-5A, I _B =-500mA			-1.2	V
Base-Emitter Turn-On Voltage(Note)	V _{BE(ON)}	I _C =-2A, V _{CE} =-2V			-0.9	V
Dc Current Gain (Note)	h _{FE}	V _{CE} =-2V, I _C =-500mA	400			
		V _{CE} =-2V, I _C =-1A	350			
		V _{CE} =-2V, I _C =-2A	300			
		V _{CE} =-2V, I _C =-4A	120			
		V _{CE} =-2V, I _C =-5A	50			
Transition Frequency	f _T	V _{CE} =-10V, I _C =-100mA, f=100MHz	80			MHz

Note: Pulse test: t_p ≤ 300μs, Duty cycle ≤ 2%.

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